

5.5V rated 2.4A capable slew rate controlled load switch

Features

- 1.8V to 5.5V operation voltage range
- Low quiescent current < 1µA when disabled
- Reverse current blocking when switch is off
- Built-in 100Ω(typ) output discharge resistor
- 40mΩ N-MOSFET
- DC Current Up to 2.4A
- Peak Current Up to 5A
- Built-in Soft-Start 3ms
- Active High with Integrated Bridge
- Pb-Free Device DFN-4 1.2x1.6mm

Applications

- Cell Phone and Digital Camera
- PDA and Notebook
- LCD Monitor
- TV and Set-Top Box

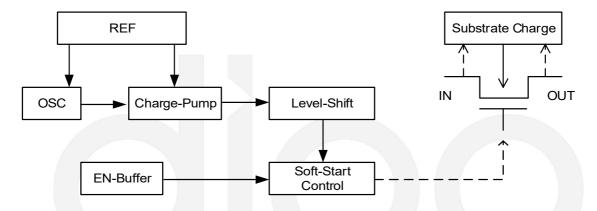
Descriptions

The DIO7330B is a Low On-Resistance N-channel MOSFET controlled by a soft-start sequence of 3ms for mobile applications.

The low $R_{DS}(on)$ allows system supplying or battery charging up to DC 2.4A.The device is enable automatically if a power supply is connected on V_{IN} pin (active High) and maintained off if no power input(internal pull down).

Due to the current consumption optimization, the leakage current is drastically decreased from the battery connected to the device, which allows extending the battery life.

Block Diagram



Ordering Information

Order Part Number	Top Marking		T _A	Package		
DIO7330BDN4	YW3B	Green	-40 to 85°C	TDFN-4	Tape & Reel, 3000	



Pin Assignments

DFN-4 (TOP VIEW)

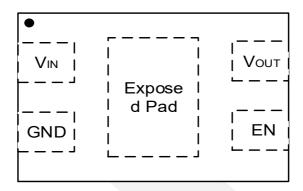


Figure 1 Pin Assignment

Pin Description

Pin	Name	Туре	Description
1	V _{IN}	Power	Switch Input voltage; connect a 1µF or greater ceramic capacitor from IN to GND as close as possible to the IC.
2	GND	Power	GND.
3	EN	Input	Enable input, logic high active.
4	Vout	Output	Switch Output; connect a $1\mu F$ capacitor from V_{OUT} to GND as close as possible to the IC.
	Exposed Pad	Power	Exposed pad can be connected to GND plane for dissipation purpose or any other thermal plane.



Absolute Maximum Ratings

Stresses beyond those listed under "Absolute Maximum Rating" may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other condition beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

	Parameter	Rating	Unit	
V _{IN}		-0.3 to 6	V	
V _{OUT} , EN		-0.3 to 6	V	
Storage Temperature		-65 to 150	°C	
Maximum Junction Ra	nge	-40 to 145	°C	
Thermal Resistance, θ	JA	170	°C/W	
Power Dissipation, (T _A =25°C)		580	mW	
Latch Up Protection	Latch Up Protection 200		mA	
ESD	HBM, JEDEC: JESD22-A114	6	141/	
	CDM, JEDEC : JESD22-C101	2	kV	

Recommended Operating Conditions

The Recommended Operating Conditions table defines the conditions for actual device operation to ensure optimal performance to the datasheet specifications. DIOO does not recommend exceeding them or designing to Absolute Maximum Ratings.

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
V _{IN}	Operational Power Supply		1.8		5.5	V
V _{EN}	Enable Voltage		0		5.5	V
C _{IN}	Decoupling input capacitor		1			μF
C _{OUT}	Decoupling output capacitor	USB port per Hub	1			μF
I _{OUT}	Maximum DC Current	T _A =25°C			3	Α
I _{PEAK}	Maximum Peak Current	1ms pulse width at 217Hz ,T _A =25°C			5	Α
T _A	Ambient Temperature Range		-40	25	85	°C
TJ	Junction Temperature Range		-40	25	125	°C



Electrical Characteristics

T_A=25°C V_{IN}=5V, unless otherwise noted.

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Symbol	Parameter	Conditions		Min.	Тур.	Max.	Unit	
POWER SI	WITCH							
R _{DS(ON)}	Static drain-source on-state resistance	V _{IN} =1.8~5.5V, T _A = 25°C			40		mΩ	
		I _{OUT} =200mA, -40°C< T _A <85°C				70	mΩ	
t _R	Switch turn-on edge rising time	V _{IN} =4.5V	C_{LOAD} =100 μ F, R_{LOAD} =150 Ω	2	2.5	5	ms	
t _F	Switch turn-off edge falling time	V _{IN} =4.5V	C_{LOAD} =100μF, R_{LOAD} =150 Ω		3		ms	
t _{DON}	Switch turn-on delay	V _{IN} =4.5V; C _{LOAD} =100μF	50% of EN pin to V _{OUT} =10% of fully on		1.5		ms	
t _{DOFF}	switch turn-off delay	V _{IN} =4.5V; C _{LOAD} =100μF	50% of EN pin to V _{OUT} =90% of fully on		10		μs	
ENABLE II	NPUT EN			I	I	Į.		
V _{IH}	High-level input voltage			1.45			٧	
V _{IL}	Low-level input voltage					0.85	٧	
R _{PD}	Pull-down resistance at EN pin	T _A = -45°C to 85°C			1		МΩ	
REVERSE-	LEAKAGE PROTECTION	İ						
I _{REV}	Reverse-current protection	V _{IN} =0V, V _{OUT} =4.2V, -40°C< T _A <85°C, EN="0"			1	2	μΑ	
QUIESCENT CURRENT								
IQ	Current consumption	V _{IN} =5V, V _{OUT} floating, EN=5V			100	180	μΑ	
I _{SDN}	shutdown current	V _{IN} =5V, En="0", -40°C< T _A <85°C				1	μΑ	
R _{DR}	Output Discharge resistor	V _{IN} =5V, En="0"		100		Ω		
L	1	1		1	1	l		

Note: This parameter is guaranteed by design and characterization.



Application Information

Enable

Enable pin voltage in the active high means on. This part is automatically turned on when the input voltage enables the device. In the other side, this part is turned off when the input voltage is not available, which limits current consumption from battery to V_{OUT} pin.

Input Capacitor

To limit the voltage drop on the input supply caused by transient inrush currents, an input capacitor is placed to the V_{IN} and GND as close as possible. The value of the input capacitor is recommended 1µF at least. Higher values capacitor can help to further reduce the voltage drop.

Output Capacitor

While the device works, a capacitor from 100nF to 1μ F across V_{OUT} and GND is recommended to accommodate load transient condition. It also helps to prevent parasitic inductance forces V_{OUT} below GND when switching off. Output capacitor has the minimal effect on device's turn on slew rate time.

Blocking Control

The blocking control circuitry switches the bulk of the power NMOS. When the part is off (No V_{IN} or EN tied to GND externally), the body diode limits the leakage current I_{REV} from OUT to IN. In this condition, the anode of the body diode is connected to IN pin and the cathode is connected to OUT pin. During the operation, the anode of the body diode is connected to OUT pin and the cathode is connected to IN pin to prevent the discharge of the power supply.



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